

Real Time Clock Module

Model RTC-58321

Features

Built-in crystal oscillator

- · eliminates need for external components
- · eliminates design time
- · reduces board space

Low current consumption

Low-voltage battery backup function

4-bit bidirectional multiplexed address/data bus

Counter start, stop and reset functions

12 or 24 hour format, automatic leap year selection

Interrupt signal outputs: 1024, 1, 1/60, 1/3600 Hz

Standard 16-pin DIP, pin-compatible with MSM 58321RS



Description

The RTC-58321 Real Time Clock Module incorporates a CMOS real time clock and a complete crystal oscillator in a standard 16-pin DIP. The combination of the real time clock and crystal oscillator in one package eliminates the need for an external crystal, resistors, and capacitors, resulting in a substantial reduction in design time and board space, as well as procurement, inventory, testing, and assembly costs. Application note available upon request.

Electrical Characteristics

Operating Ranges

Item	Symbol	Conditions	Range	Units
Supply voltage	V _D D		4.5~5.5	V
Data-holding voltage ¹	V _{DH}		2.2~5.5	V
Crystal frequency	fo		32.768	kHz
Operating temperature	Top		-10~+60	℃

Guarantees continued clock operation only.

Absolute Maximum Patings

Item	Symbol	Conditions	Rated Value	Units	
Supply voltage	V _{DD}	Ta=25℃	-0.3~7	V	
Input voltage	Vı	Ta=25°C	GND-0.3~V _{DD} +0.3	V	
Output voltage	Vo	Ta=25℃	GND-0.3~V _{DD} +0.3	V	
Storage temperature	Tstg		-30~+80	℃	

Flectrical Characteristics

 $V_{-1} = 5V + 5\%$ $T_2 = -10 \sim +60\%$

lectrical Character	istics	V	$_{DD} = 5V$	±5%	a = -10	~ +607
Item	Symbol	Conditions	MIN	TYP	MAX	Unit
H. input voltage ^{1,2}	VIHI		3.6	-	_	V
put voltago	V _{IH 2}		V _{DD} -0.5	-		V
. input voltage	VIL				0.8	V
L. output voltage	VoL	$I_0 = I.6mA$			0.4	V
L. output current	loL	V ₀ = 0.4V	1.6		_	mA
H. input current ³	I _{IH}	$V_1 = 5V$	10	30	80	μА
L. input current ³	I _{IL}	V1=0V			-1	μА
D ₀ ~ D ₃ terminals input off-leak current	I _{LIH} /I _{LIL}	V,=5V V,=0V			1 -1	μΑ
Input capacity	Cı	f=IMHz		5		pF
Current consumption	I _{o P}	Ta = 25 °C V _{DD} =5V/V _{DD} =3V	-	16.5/6.2	30.0/10.0	μА
Accuracy ⁴	△t/t	Ta=25℃ V _{DD} =5V		-	± 4.5	sec/day

CS2 WRITE, READ, ADDRESS-WRITE, STOP, TEST, D₀~D₃ terminals

Function Table

	AC		Addres	s Input			Address	s Outpu	t					
Internal Counter	Address	D ₃	D ₂	D, (A,)	D ₀ (A ₀)	D ₃	Dz	D,	D ₀	Count Value	Remarks			rks
Sı	0	L	L	L	L	*	*	*	*	0 ~ 9				
S ₁₀	T	L	L	L	Н		*	*	*	0 ~ 5				
MI	2	L	L	Н	L	*	*	*	*	0 - 9				
MI10	3	L	L	Н	Н		*	*	*	0 ~ 5				
Н,	4	L	Н	L	L	*	*	*	*	0 ~ 9				
H 10	5	L	Н	L	н	*	*	*	*	0 - 1	hour cloc the D2 b	24-hi k. W it is	our c hen rese	r a.m., clock, L for 12- D3 H is writte t inside the IC antly at L.
W	6	L	Н	Н	L		*	*	*	0 - 6				
D,	7	L	Н	Н	Н	*	*	*	*	0 ~ 9				
Dio	8	Н	L	L	L	*2	*2	*	*	0 ~ 3	D2 and D3 in	the D10	Oline ar	e for leap year select
MO ₁	9	Н	L	L	Н	*	*	*	*	0 - 9	Calendar	D ₃	D ₂	Remainder when divided years by 4
MO ₁₀	Α	Н	L	Н	L				*	0 ~ 1	Western	L	L	0
Υ.	В	Н	L	Н	Н	*	*	*	*	0 ~ 9	Japanese	L	H	3 2
Y 10	С	Н	Н	L	L	*	*	*	*	0 ~ 9		Н	Н	1
	D	Н	Н	L	Н						These selections are for resetting the 5-stage and the BUSY circulater the 1/215 frequency stage. Resetting is activated by latchin this code on to the address late and setting the WRITE input to H.			
	E f	н	Н	н	L/H	1/3600 HZ	1/60 Hz	1 Hz	1024 Hz		These selections are for obtainin standard signals. By latching th code on to the address latch an setting READ to H, the standard signals will be output at Do – Da			

Note 1. The blank spaces in the data input/output columns indicate that there are no bits. When READ is performed, the L level is output. When WRITE is performed nothing will be stored in the memory because thre are no bits.

Note 2: The bit indicated by the symbol *1 is for selecting the 12hr/24hr clock and those indicated by *2 are for leap year selection. READ and WRITE are possible with all three bits.

Note 3: For address input, send a signal to the D₀ ~ D₃ bus line, then input

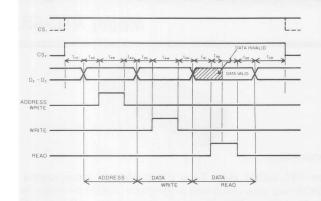
ADDRESS WRITE. The ADDRESS data will be latched on to the address latch.

²CS1 terminals

³CS1, CS2, WRITE, READ, ADDRESS-WRITE, STOP, TEST terminals

⁴Tighter accuracy available, contact factory Specifications subject to change without notice

Write & Read Timing



 $(Ta = 25^{\circ}C \quad V_{DD} = 5V \pm 5\%)$

Item	Symbol	MIN	TYP	MAX	Units	
CS set-up time	tcs	0			μS	
Address set-up time	tas	0			μS	
Address write pulse range	taw	0.5			μS	
Address hold time	tan	0.1			μS	
Data set-up time	tos	0	_		μS	
Write pulse range	tww	2			μS	
Data hold time	t _{DH}	0		-	μS	
Read inhibit time	t _{RI}	0			μS	
Read access time	tra		-	*	μS	
Read delay time	too			1	μS	
CS hold time	tch	0			μS	

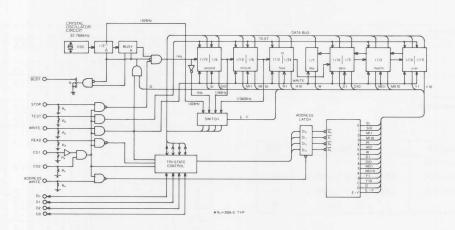
 $*t_{RA} = 1\mu S + CRIn \left(\frac{V_{DD}}{V_{DD}-VH}\right)$

C: Data line wiring capacity R: Pull-up resistance value

VH: "H" input voltage of the IC connected to the data line
In: Natural logarithms

Specifications subject to change without notice.

Circuit Diagram



Pin Connections



(Top View)

1. CS ₂	16. V _{DD}
2. WRITE	15. NC
3. READ	14. NC
4. Do	13. CS ₁
5. D ₁	12. TEST
6. D ₂	11. STOP
7. D ₃	10. BUSY
8. Vss	9. ADDRESS

NC: Do not connect externally.

Package Dimensions

